2SD1609

Rev.F Mar.-2016

蓝箭电子 BLUE ROCKET ELECTRONICS

DATA SHEET

/ Descriptions

WR0459 ṂṂ Ƭ QSQ ÆṀ ч s ‖ ㄱ Silicon NPN transistor in a TO-126 Plastic Package.

/ Features

лъ 5VE443< Ӣ ´

Complementary pair with 2SB1109.

/ Applications

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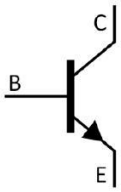
Low frequency high voltage amplifier.

/ Equivalent Circuit



/ Pinning

PIN1 χ Emitter PIN 2 χ Collector PIN 3 χ Base

/ h_{FE} Classifications & Marking

h_{FE} Classifications Symbol	B	C	D
h_{FE} Range	60 120	100 200	160 320

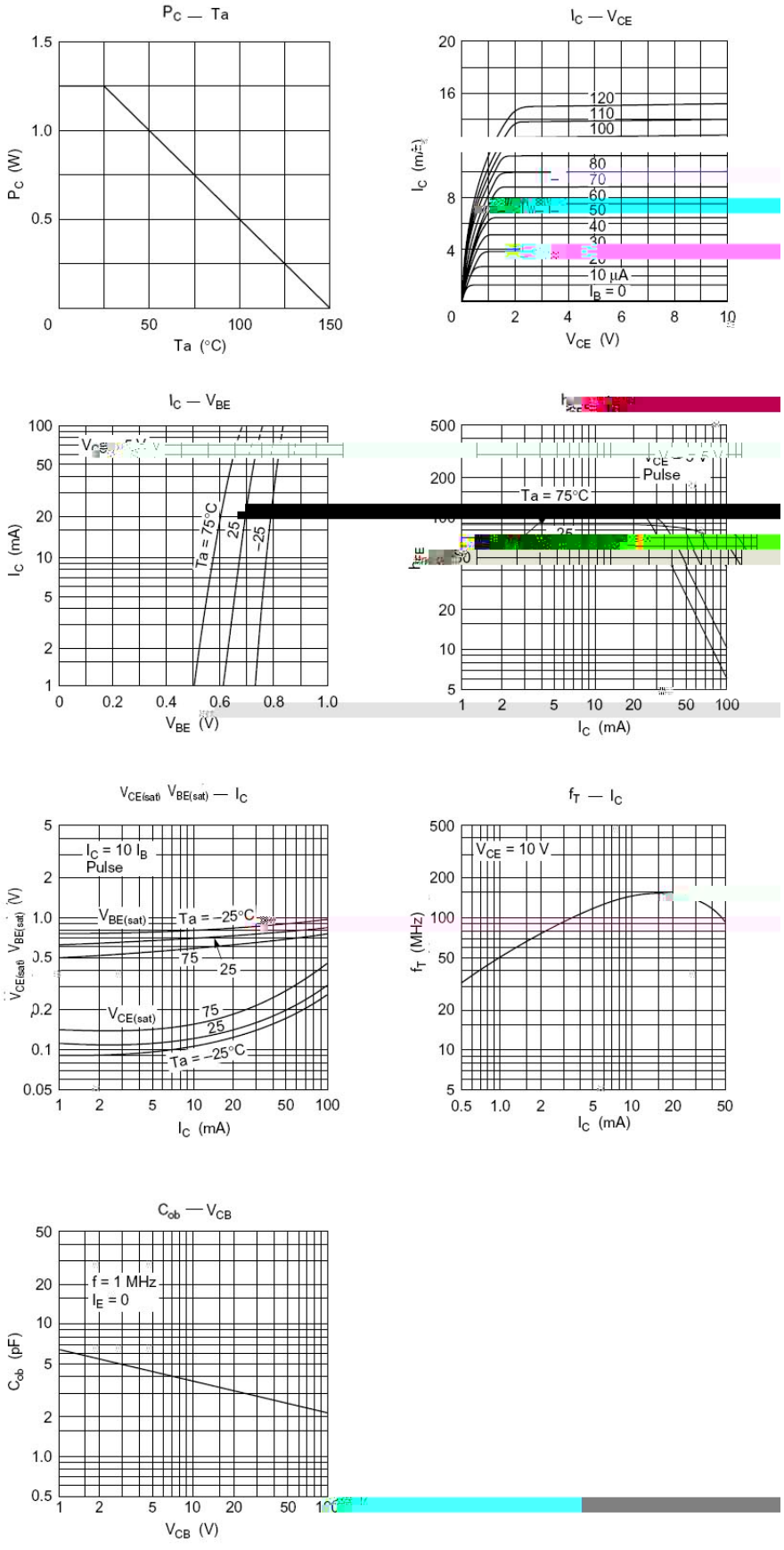
/ Absolute Maximum Ratings(Ta=25)

v ̈Ω Parameter	ϒ N Symbol	̈Ω Ö Rating	D Ч Unit
Collector to Base Voltage	V_{CBO}	160	V
Collector to Emitter Voltage	V_{CEO}	160	V
Emitter to Base Voltage	V_{EBO}	5	V
Collector Current - Continuous	I_C	100	mA
Collector Power Dissipation	P_C	1.25	W
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 150	

/ Electrical Characteristics(Ta=25)

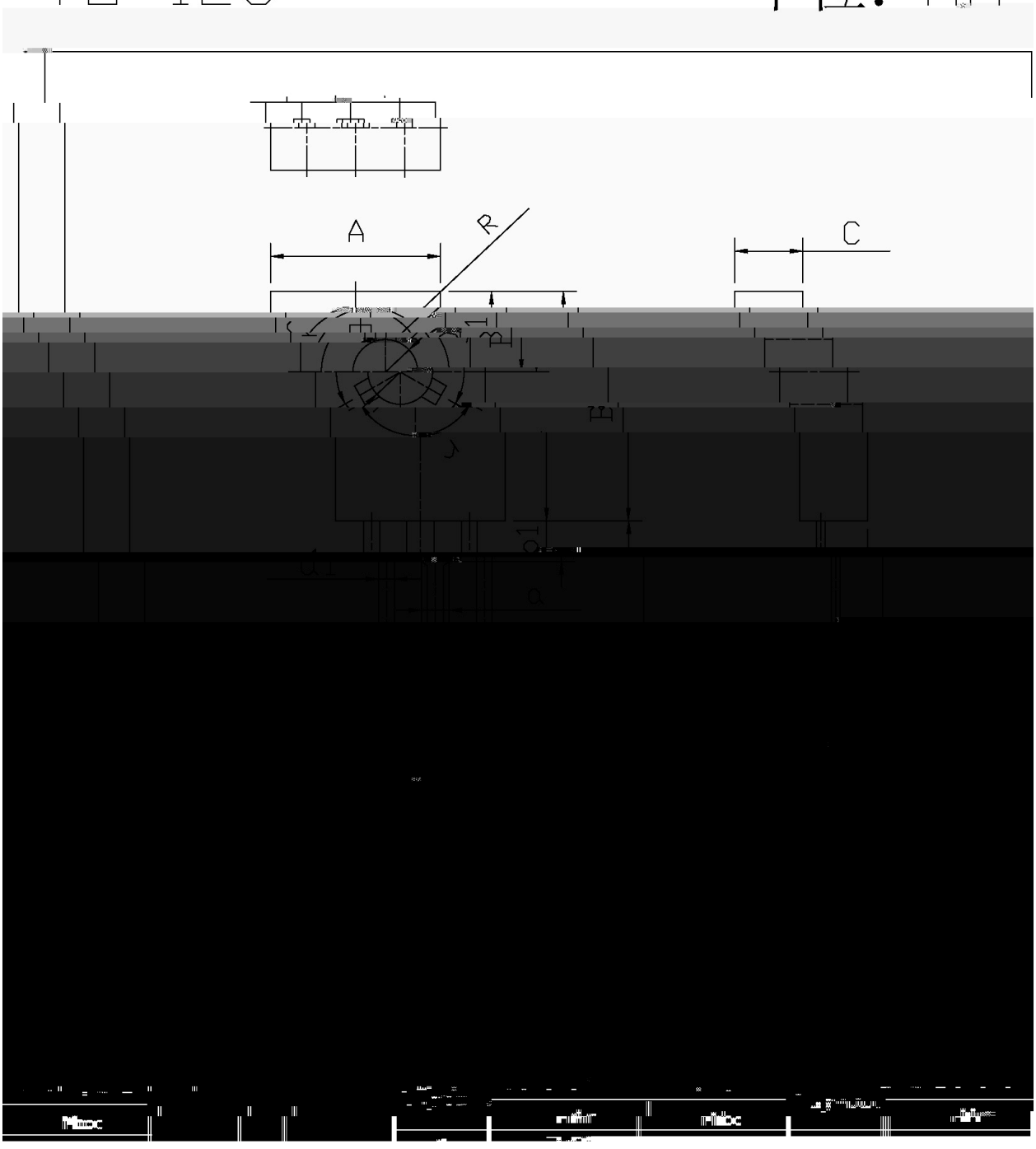
v ̈Ω Parameter	ϒ N Symbol	Ш :† ţ Test Conditions	ώ ņ Ö Min	Ɛ ʒ Ö Typ	ώ ᶻ Ö Max	D Ч Unit
Collector to Base Breakdown Voltage	V_{CBO}	I_C=10μA I_E=0	160			V
Collector to Emitter Breakdown Voltage	V_{CEO}	I_C=1mA I_B=∞	160			V
Emitter to Base Breakdown Voltage	V_{EBO}	I_E=10μA I_C=0	5			V
Collector Cut-Off Current	I_{CBO}	V_{CB}=140V I_E=0			10	μA
DC Current Gain	$h_{FE(1)}$	V_{CE}=5V I_C=10mA	60		320	
	$h_{FE(2)}$	V_{CE}=5V I_C=1mA	30			
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	I_C=30mA I_B=3mA			2	V
Base to Emitter Voltage	V_{BE}	V_{CE}=5V I_C=10mA			1.5	V
Transition Frequency	f_T	V_{CE}=5V I_C=10mA		140		MHz
Collector Output Capacitance	C_{ob}	V_{CB}=10V I_E=0 f=1MHz		3.8		pF

/ Electrical Characteristic Curve

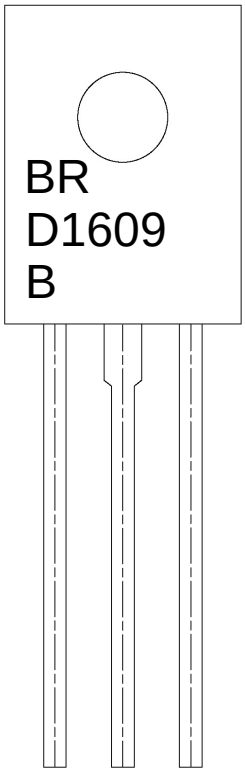


/ Package Dimensions

TO-126 单位：mm



/ Marking Instructions



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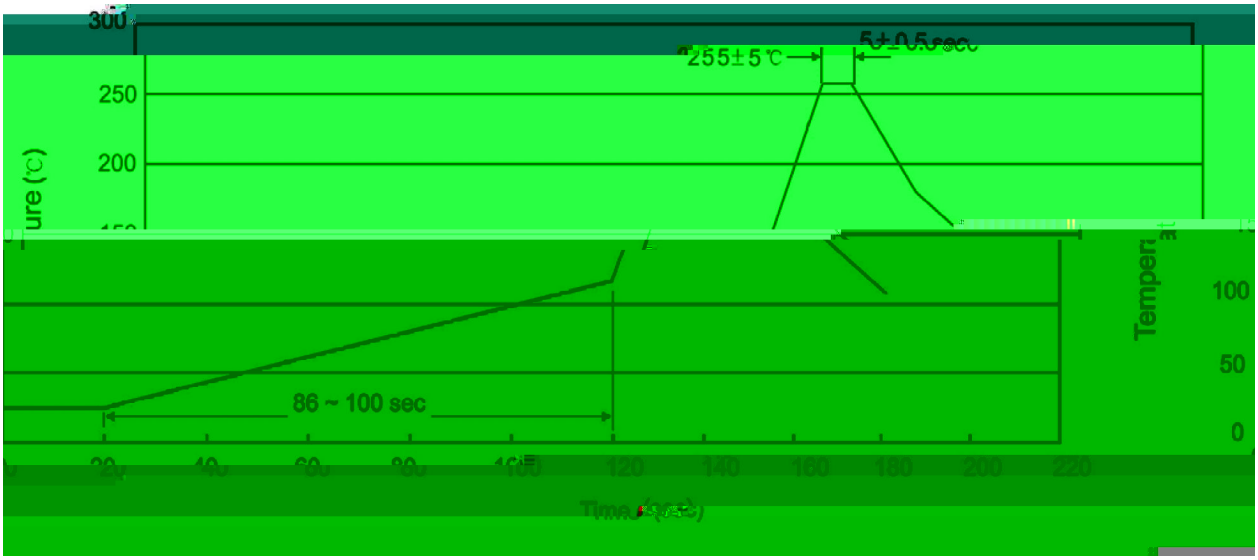
Note:

BR:	Company Code
D1609:	Product Type.
B:	h_{FE} Classifications Symbol
****:	Lot No. Code, code change with Lot No.

( ) / Temperature Profile for Dip Soldering(Pb-Free)



ب ˝ χ

1 Ĺ ♬ □ ỷ 25 Ḱ 150 ł ı ˋH ڑ 60 Ḱ 90sec;

2 Š Ө □ ỷ 255 ° 5 ł ı ˋH ڑ ˋY ﾊ ㎛ 5 ° 0.5sec;

3 ì ˙ ﾘ ˛ ɔ ෯ ỷ ㎛ 2 Ḱ 10 ł /sec.

Note:

1.Preheating:25~150 ł , Time:60~90sec.

2.Peak Temp.:255 ° 5 ł , Duration:5 ° 0.5sec.

3. Cooling Speed: 2~10 ł /sec.

/ Resistance to Soldering Heat Test Conditions

□ ỷ χ 270 ° 5 ł	ˋH ڑ χ 10 ° 1 sec.	Temp.:270±5	Time:10±1 sec

/ Packaging SPEC.

ˈQ ţ ﾘ Ł / BULK

Package Type	Units